**ELECTRICAL CHARACTERISTICS** ($T_C$ = 25°C unless otherwise noted) (Note 2)

| Characteristic | Symbol | Min | Max | Unit |
|---|---|---|---|---|
| **OFF CHARACTERISTICS** | | | | |
| Collector−Emitter Sustaining Voltage (Note 3) ($I_C$ = 100 mAdc, $I_B$ = 0) | $V_{CEO(sus)}$ | | | Vdc |
| 2N6111, 2N6288 | | 30 | − | |
| 2N6109 | | 50 | − | |
| 2N6107, 2N6292 | | 70 | − | |
| Collector Cutoff Current | $I_{CEO}$ | | | mAdc |
| ($V_{CE}$ = 20 Vdc, $I_B$ = 0) | | | | |
| 2N6111, 2N6288 | | − | 1.0 | |
| ($V_{CE}$ = 40 Vdc, $I_B$ = 0) | | | | |
| 2N6109 | | − | 1.0 | |
| ($V_{CE}$ = 60 Vdc, $I_B$ = 0) | | | | |
| 2N6107, 2N6292 | | − | 1.0 | |
| Collector Cutoff Current | $I_{CEX}$ | | | |
| ($V_{CE}$ = 40 Vdc, $V_{EB(off)}$ = 1.5 Vdc) | | | | |
| 2N6111, 2N6288 | | − | 100 | μAdc |
| ($V_{CE}$ = 60 Vdc, $V_{EB(off)}$ = 1.5 Vdc) | | | | |
| 2N6109 | | − | 100 | |
| ($V_{CE}$ = 80 Vdc, $V_{EB(off)}$ = 1.5 Vdc) | | | | |
| 2N6107, 2N6292 | | − | 100 | |
| ($V_{CE}$ = 30 Vdc, $V_{EB(off)}$ = 1.5 Vdc, $T_C$ = 150°C) | | | | |
| 2N6111, 2N6288 | | − | 2.0 | mAdc |
| ($V_{CE}$ = 50 Vdc, $V_{EB(off)}$ = 1.5 Vdc, $T_C$ = 150°C) | | | | |
| 2N6109 | | − | 2.0 | |
| ($V_{CE}$ = 70 Vdc, $V_{EB(off)}$ = 1.5 Vdc, $T_C$ = 150°C) | | | | |
| 2N6107, 2N6292 | | − | 2.0 | |
| Emitter Cutoff Current ($V_{BE}$ = 5.0 Vdc, $I_C$ = 0) | $I_{EBO}$ | − | 1.0 | mAdc |
| **ON CHARACTERISTICS** (Note 3) | | | | |
| DC Current Gain | $h_{FE}$ | | | − |
| ($I_C$ = 2.0 Adc, $V_{CE}$ = 4.0 Vdc) | | | | |
| 2N6107, 2N6292 | | 30 | 150 | |
| ($I_C$ = 2.5 Adc, $V_{CE}$ = 4.0 Vdc) | | | | |
| 2N6109 | | 30 | 150 | |
| ($I_C$ = 3.0 Adc, $V_{CE}$ = 4.0 Vdc) | | | | |
| 2N6111, 2N6288 | | 30 | 150 | |
| ($I_C$ = 7.0 Adc, $V_{CE}$ = 4.0 Vdc) | | | | |
| All Devices | | 2.3 | − | |
| Collector−Emitter Saturation Voltage ($I_C$ = 7.0 Adc, $I_B$ = 3.0 Adc) | $V_{CE(sat)}$ | − | 3.5 | Vdc |
| Base−Emitter On Voltage ($I_C$ = 7.0 Adc, $V_{CE}$ = 4.0 Vdc) | $V_{BE(on)}$ | − | 3.0 | Vdc |
| **DYNAMIC CHARACTERISTICS** | | | | |
| Current Gain − Bandwidth Product (Note 4) | $f_T$ | | | MHz |
| ($I_C$ = 500 mAdc, $V_{CE}$ = 4.0 Vdc, $f_{test}$ = 1.0 MHz) | | | | |
| 2N6288, 2N6292 | | 4.0 | − | |
| 2N6107, 2N6109, 2N6111 | | 10 | − | |
| Output Capacitance ($V_{CB}$ = 10 Vdc, $I_E$ = 0, f = 1.0 MHz) | $C_{ob}$ | − | 250 | pF |
| Small−Signal Current Gain ($I_C$ = 0.5 Adc, $V_{CE}$ = 4.0 Vdc, f = 50 kHz) | $h_{fe}$ | 20 | − | − |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Indicates JEDEC Registered Data.
3. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.
4. $f_T = |h_{fe}| \bullet f_{test}$

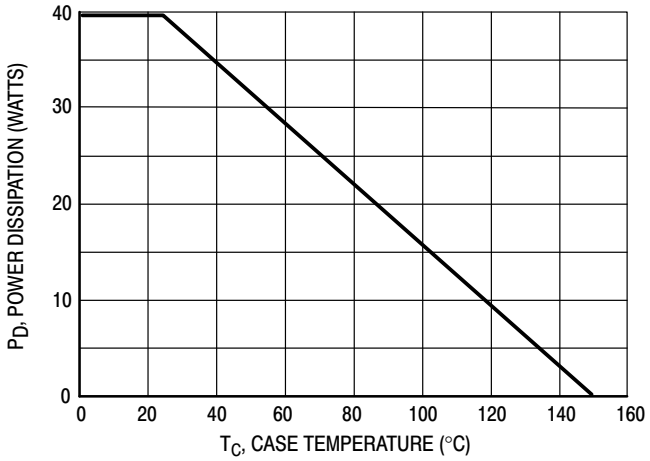



**Figure 1. Power Derating**

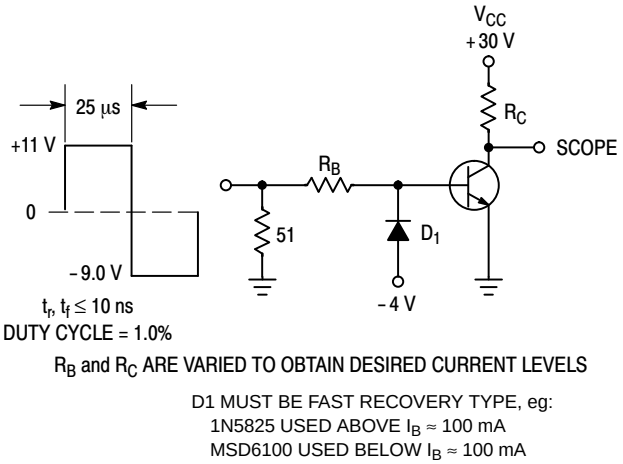



**Figure 2. Switching Time Test Circuit**

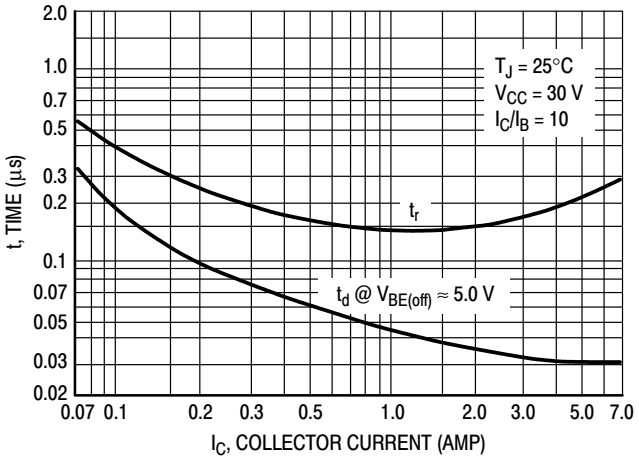



**Figure 3. Turn−On Time**

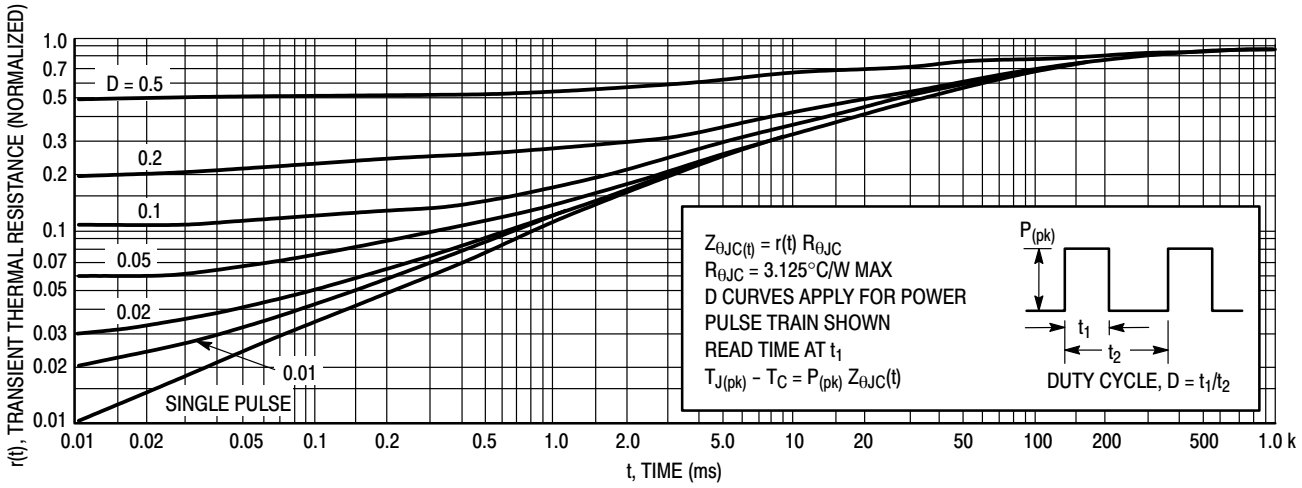



**Figure 4. Thermal Response**

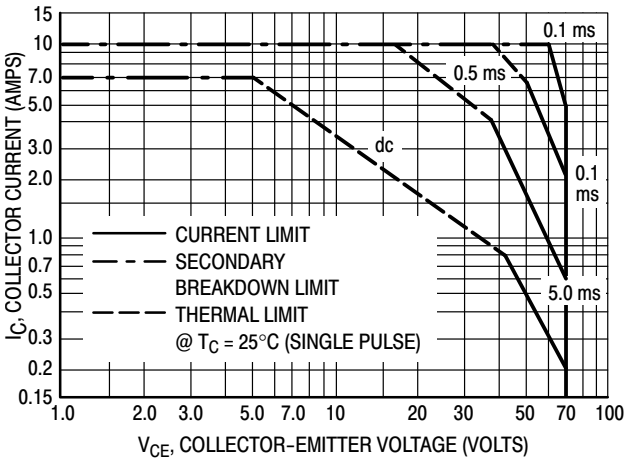



**Figure 5. Active−Region Safe Operating Area**

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)}$ = 150°C; $T_C$ is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150°C$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

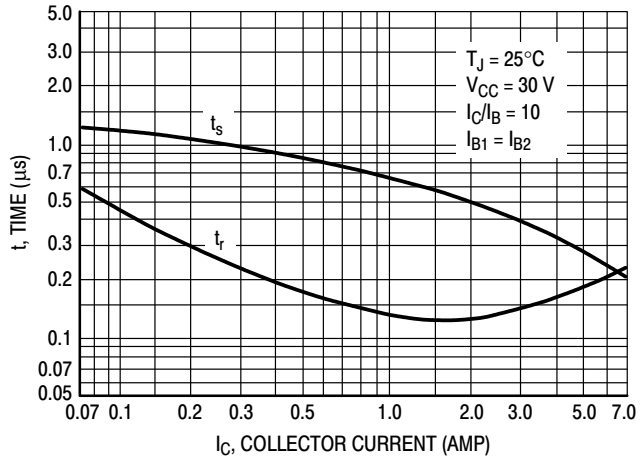



**Figure 6. Turn−Off Time**

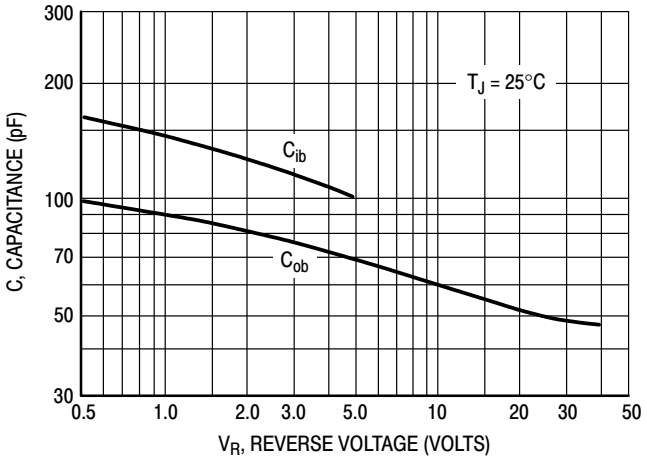



**Figure 7. Capacitance**

**ORDERING INFORMATION**

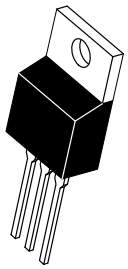
| Device | Device Marking | Package | Shipping |
|---|---|---|---|
| 2N6107G | 2N6107 | TO−220 (Pb−Free) | 50 Units / Rail |
| 2N6109G | 2N6109 | TO−220 (Pb−Free) | 50 Units / Rail |
| 2N6111G | 2N6111 | TO−220 (Pb−Free) | 50 Units / Rail |
| 2N6288G | 2N6288 | TO−220 (Pb−Free) | 50 Units / Rail |
| 2N6292G | 2N6292 | TO−220 (Pb−Free) | 50 Units / Rail |

# MECHANICAL CASE OUTLINE
## PACKAGE DIMENSIONS

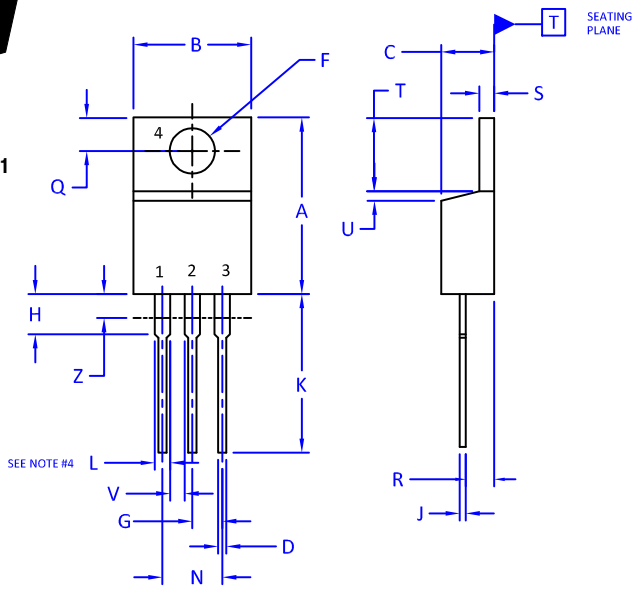
ON Semiconductor®

**TO−220**
CASE 221A−09
ISSUE AJ

DATE 05 NOV 2019



SCALE 1:1




NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 2009.
2. CONTROLLING DIMENSION: INCHES
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.
4. MAX WIDTH FOR F102 DEVICE = 1.35MM

| | INCHES | | MILLIMETERS | |
|---|---|---|---|---|
| DIM | MIN. | MAX. | MIN. | MAX. |
| A | 0.570 | 0.620 | 14.48 | 15.75 |
| B | 0.380 | 0.415 | 9.66 | 10.53 |
| C | 0.160 | 0.190 | 4.07 | 4.83 |
| D | 0.025 | 0.038 | 0.64 | 0.96 |
| F | 0.142 | 0.161 | 3.60 | 4.09 |
| G | 0.095 | 0.105 | 2.42 | 2.66 |
| H | 0.110 | 0.161 | 2.80 | 4.10 |
| J | 0.014 | 0.024 | 0.36 | 0.61 |
| K | 0.500 | 0.562 | 12.70 | 14.27 |
| L | 0.045 | 0.060 | 1.15 | 1.52 |
| N | 0.190 | 0.210 | 4.83 | 5.33 |
| Q | 0.100 | 0.120 | 2.54 | 3.04 |
| R | 0.080 | 0.110 | 2.04 | 2.79 |
| S | 0.045 | 0.055 | 1.15 | 1.41 |
| T | 0.235 | 0.255 | 5.97 | 6.47 |
| U | 0.000 | 0.050 | 0.00 | 1.27 |
| V | 0.045 | ---- | 1.15 | --- |
| Z | ---- | 0.080 | --- | 2.04 |

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 2:
PIN 1. BASE
2. EMITTER
3. COLLECTOR
4. EMITTER

STYLE 3:
PIN 1. CATHODE
2. ANODE
3. GATE
4. ANODE

STYLE 4:
PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. MAIN TERMINAL 2

STYLE 5:
PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN

STYLE 6:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. CATHODE

STYLE 7:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. ANODE

STYLE 8:
PIN 1. CATHODE
2. ANODE
3. EXTERNAL TRIP/DELAY
4. ANODE

STYLE 9:
PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 10:
PIN 1. GATE
2. SOURCE
3. DRAIN
4. SOURCE

STYLE 11:
PIN 1. DRAIN
2. SOURCE
3. GATE
4. SOURCE

STYLE 12:
PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. NOT CONNECTED

| | | |
|---|---|---|
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